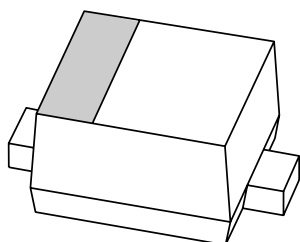


DATA SHEET



PMEG2005EB

Low V_F MEGA Schottky barrier
diode

Product specification
Supersedes data of 2003 Feb 20

2003 Apr 04

Low V_F MEGA Schottky barrier diode

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FEATURES

- Forward current: 0.5 A
- Reverse voltage: 20 V
- Very low forward voltage
- Guard ring protected
- Ultra small SMD package.

APPLICATIONS

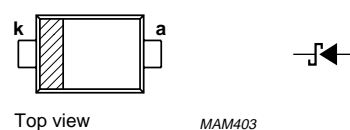
- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Low current rectification
- Low power consumption applications (e.g. handheld devices).

DESCRIPTION

Planar Maximum Efficiency General Application (MEGA) Schottky barrier diode, encapsulated in a SOD523 (SC-79) ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



Marking code: L5.

The marking bar indicates the cathode.

Fig.1 Simplified outline (SOD523; SC-79) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		–	20	V
I_F	continuous forward current		–	500	mA
I_{FRM}	repetitive peak forward current	$t_p = 1 \text{ ms}; \delta \leq 0.25$	–	3.5	A
I_{FSM}	non-repetitive peak forward current	$t = 8 \text{ ms square wave}$	–	6	A
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	125	°C
T_{amb}	operating ambient temperature		–65	+125	°C

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ELECTRICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V_F	continuous forward voltage	see Fig.2			
		$I_F = 0.1\text{ mA}$	120	180	mV
		$I_F = 1\text{ mA}$	180	240	mV
		$I_F = 10\text{ mA}$	245	290	mV
		$I_F = 100\text{ mA}$	320	380	mV
		$I_F = 500\text{ mA}$	430	480	mV
I_R	continuous reverse current	$V_R = 10\text{ V}$; see Fig.3; note 1	7	30	μA
C_d	diode capacitance	$V_R = 1\text{ V}$; $f = 1\text{ MHz}$; see Fig.4	24	30	pF

Note

1. Pulsed test: $t_p = 300\text{ }\mu\text{s}$; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\text{ j-a}}$	thermal resistance from junction to ambient	note 1	400	K/W

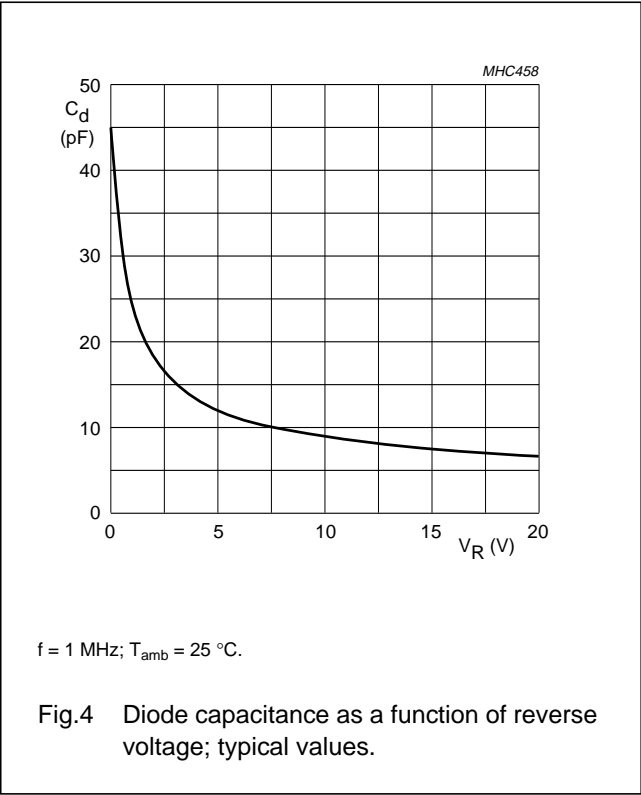
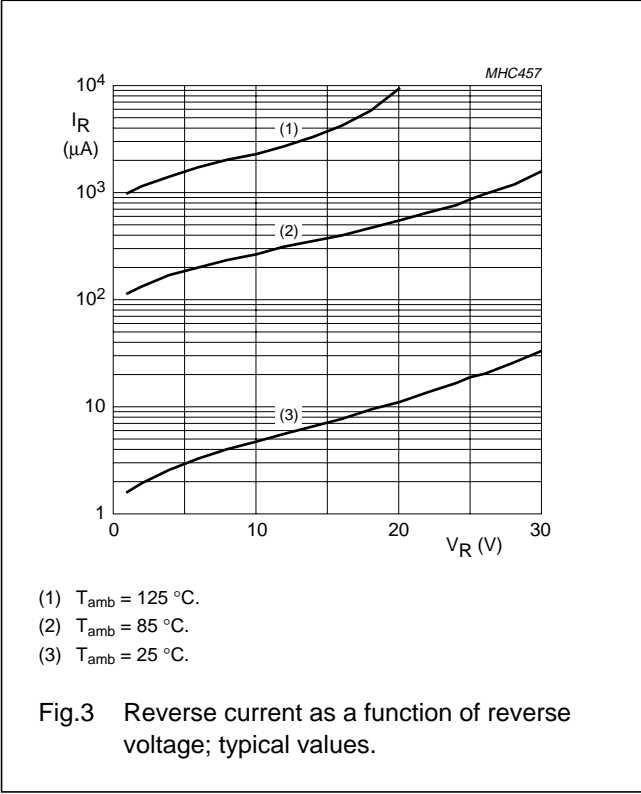
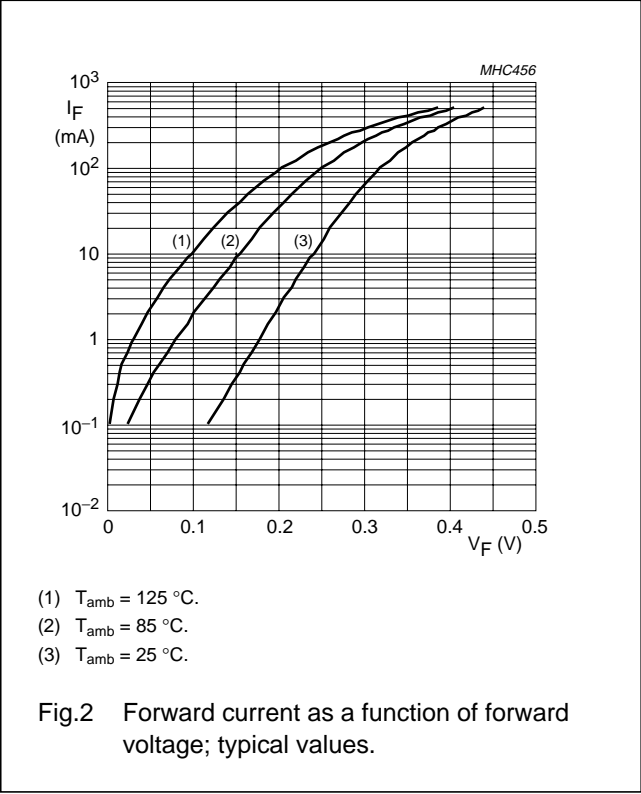
Note

1. Refer to SOD523 (SC-79) standard mounting conditions.

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GRAPHICAL DATA



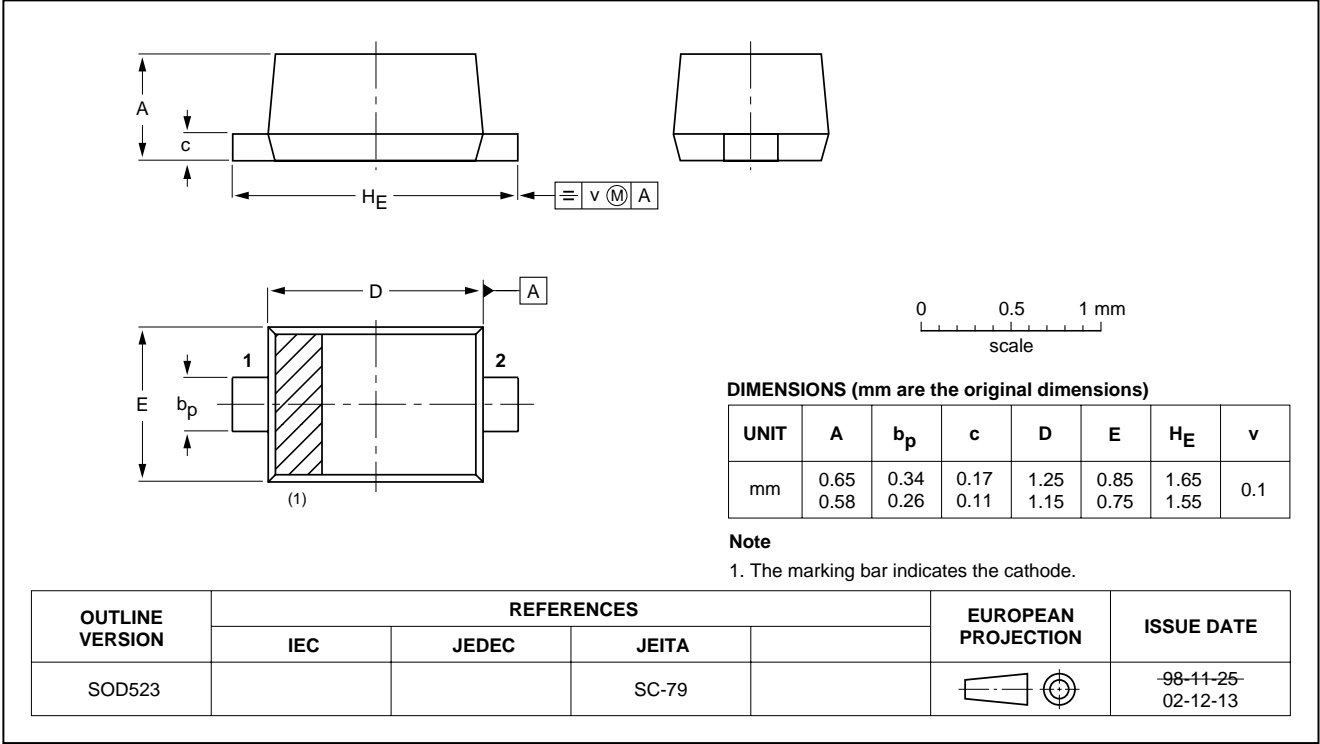
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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD523



Low V_F MEGA Schottky barrier diode

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

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NOTES

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